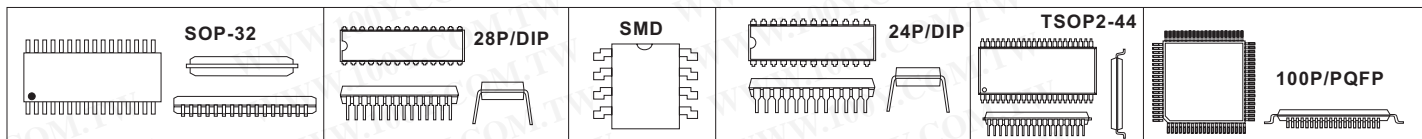


SRAM

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Size	Organisation	Access Time
1597	HM6116LM-70	HMC	SRAM 16K	24P/SOP	16K	2K*8	70ns
19028	HM6116P-70L	HITACHI	SRAM	DIP			
19057	HM6264LM-70	HMC	SRAM	SMD	8K*8	8192*8	70ns
40196	HM6264LP-15	HMC	8192-WORD X 8-BIT HIGH SPEED CMOS STATIC RAM	28P/DIP	8K*8	8192*8	150NS
17171	HM6264LP-70	HMC	SRAM	28P/DIP	8K*8	8192*8	70ns
19058	HM6264WM-70L	HMC	SRAM	28P/SOP	8K*8	8192*8	70ns
19059	HM628128DLFP-55SL	HITACHI	1 M SRAM (128-kword*8-bit)	32P/SOP	1M	128K*8	55ns
33595	HM628511HJP-15	HITACHI	4M High Speed SRAM (512-kword x 8-bit)	36-pin plastic SOJ	4M	512-kword x 8-bit	15 ns
35487	HM628512CLFP-5	HITACHI	4 M SRAM	32P/SOP	4M	512K*8	55 ns
19060	HM628512CLFP-5SL	HITACHI	4M-SRAM	32P/SOIC			
33596	HM628512CLP-5SL	HITACHI	4 M SRAM (512-kword x 8-bit)	32-pin plastic DIP	4 M	512-kword x 8-bit	55 ns
4488	HM62V8128BLT-12	HITACHI	SRAM	32P/TSOP	1M	128K*8	120ns
19062	HY628100BLLG-70		128K x8 bit 5.0V Low Power CMOS slow SRAM	32P/SOP		128K*8	70ns
44806	IC61C256AH-12N	ISSI	静态式记忆体	28P/DIP	32K * 8	256K	12ns
23263	IDT6116SA45TDB	IDT	CMOS Static RAM	24P/DIP	2K*8bit	16K	45ns
23646	IS61C1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM	32P-SOJ	128K * 8	131072Word	12ns
23551	IS61C1024-15T	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/TSOP	128K * 8	131072Word	15ns
23552	IS61C256AH-15J	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/SOIC	32K * 8	256K	15ns
22626	IS61C256AH-20T	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/TSOP	32K * 8		20ns
22627	IS61C512-15N	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/DIP	64K*8		15, 20, 25, 35 ns
23553	IS61C64AH-20N	ISSI	HIGH-SPEED CMOS STATIC RAM	28P/SOIC	8K*8	64K	20ns
22631	IS61S6432-5PQ	ISSI	SYNCHRONOUS PIPELINE STATIC RAM	100P/PQFP	64K x 32		4nS
19063	IS62C1024-70Q	ISSI	128K x 8 HIGH-SPEED CMOS STATIC RAM	32P/TSOP	1M	128K*8	70ns
40556	IS62C1024-70T	ISSI	128K x 8 HIGH-SPEED CMOS STATIC RAM	32P/TSOP	1M	128K*8	70ns
39216	IS62C256-70U	ISSI	32K x 8 LOW POWER CMOS STATIC RAM	28P/SOP		32K x 8	70ns
22633	IS62LV1024LL-55H	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM	32P/TSOP	128K*8		45,55,70ns
22634	IS62LV1024LL-70T	ISSI	LOW POWER and LOW Vcc CMOS STATIC RAM	32P/TSOP	128K*8		45,55,70ns
41617	IS63LV1024-10T	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/TSOP	128K x 8		8, 10, 12 and 15 ns
22635	IS63LV1024-12J	ISSI	HIGH-SPEED CMOS STATIC RAM	32P/SOJ	128K x 8		10, 12 and 15 ns
41619	IS63LV1024-12K	ISSI	HIGH-SPEED CMOS STATIC RAM	400-mil Plastic SOJ	128K x 8		8, 10, 12 and 15 ns
41618	IS63LV1024-12T	ISSI	HIGH-SPEED CMOS STATIC RAM	TSOP	128K x 8		8, 10, 12 and 15 ns
42720	IS63LV1024-8J	ISSI	HIGH-SPEED CMOS STATIC RAM	SOJ	128K x 8		8ns
27819	K4S561632E-TL75	SAMSUNG	256Mb E-die SDRAM Specification	54P/TSOP	256M	16M*16	
46457	K6R4008V1D-UI10	SAMSUNG	静态式记忆体	TSOP2-44	2M	512K*8	10ns
19064	K6T1008C2C-DB55	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/DIP	1M	128K*8	55ns
19065	K6T1008C2C-GB55	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/SOP	1M	128K*8	55ns
34479	K6T1008C2E-DB55	SAMSUNG	128Kx8 bit Low Power CMOS Static RAM	32-DIP		128Kx8	55ns
34480	K6T1008C2E-DB70	SAMSUNG	128Kx8 bit Low Power CMOS Static RAM	32-DIP		128Kx8	70ns
19067	K6T1008C2E-GB70	SAMSUNG	128K x8 bit Low Power CMOS Static RAM	32P/SOP	1M	128K*8	70ns
23554	K6T1008C2E-GF70	SAMSUNG	Low Power CMOS Static RAM	32P/SOIC	128K*8bit		70ns
23555	K6T1008C2E-TB70	SAMSUNG	Low Power CMOS Static RAM	32P/TSOP	128K*8bit		70ns
19068	K6T4008C1B-GB55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	55ns
23556	K6T4008C1B-GP70	SAMSUNG	Low Power CMOS Static RAM	32P/SOIC	512K*8bit		70ns
19069	K6T4008C1C-GB55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	55ns
46411	K6X1008C2D-BF55	SAMSUNG	静态式记忆体	32P/SOP	128K*8		55ns
33163	K6X1008C2D-DF55	SAMSUNG	Low Power full CMOS Static RAM	32P/DIP	128K*8		55ns
23564	K6X1008C2D-DF70	SAMSUNG	Low Power full CMOS Static RAM	32P/DIP	128K*8		70ns
23565	K6X1008C2D-GB70	SAMSUNG	Low Power full CMOS Static RAM	32P/SOIC	128K*8		70ns
32111	K6X1008C2D-GF55	SAMSUNG	Low Power full CMOS Static RAM	32P/SOP	128K*8		55ns
46412	K6X1008C2D-PF70	SAMSUNG	静态式记忆体	TSOP-32	128K*8		70ns
23566	K6X1008C2D-TB70	SAMSUNG	Low Power full CMOS Static RAM	32P/TSOP	128K*8		70ns
46413	K6X4008C1F-BF55	SAMSUNG	静态式记忆体	SOP-32	4M	512K*8	55ns
46415	K6X4008C1F-BF70	SAMSUNG	静态式记忆体	32P/SOP	4M	512K*8	70ns
26222	K6X4008C1F-DF55	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/DIP	4M	512K*8	70ns
23567	K6X4008C1F-GB55T	SAMSUNG	Low Power full CMOS Static RAM	32P/SOIC	512K*8bit		55ns
25935	K6X4008C1F-GB70	SAMSUNG	512K x 8 bit Low Power CMOS Static RAM	32P/SOP	4M	512K*8	70ns
19070	KM62256CLGE-10L	SAMSUNG	32Kx8 bit Low Power CMOS Static RAM	28-SOP	256K	32Kx8	100ns
37441	KM62256CLP-7L	SAMSUNG	32Kx8 bit Low Power CMOS Static RAM	28P/DIP	256K	32Kx8	70ns
19071	KM681000BLG-7L	SAMSUNG	128K*8 bit Low Power CMOS Static RAM	SMD	1M	128K*8	32P/SOP



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